

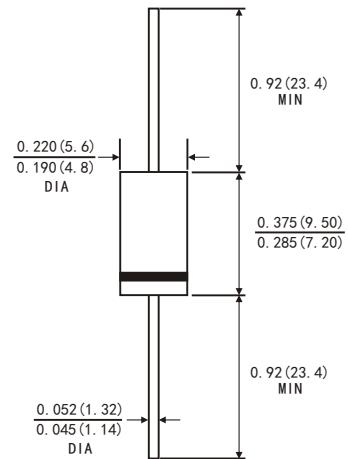
FEATURES

- Plastic package has Underwriters Laboratory Flammability Classification 94V-0
- Metal silicon junction ,majority carrier conduction
- Guard ring for overvoltage protection
- Low power loss ,high efficiency
- High current capability ,low forward voltage drop
- High surge capability
- High temperature soldering guaranteed:260°C/10 seconds at terminals
- Component in accordance to RoHS 2011/65/EU and WEEE 2012/19/EU



MECHANICAL DATA

- Case: JEDEC DO-201AD molded plastic body
- Terminals: Plated axial leads, solderable per MIL-STD-750,method 2026
- Polarity: color band denotes cathode end
- Mounting Position: Any
- Weight: 0.041ounce, 1.15 grams



Dimensions in inches and (millimetres)

TYPICAL APPLICATIONS

For use in low voltage ,high frequency inverters ,DC/DC converters, free wheeling ,and polarity protection applications

| PRIMARY CHARACTERISTICS | |
|--|-------|
| I _{F(AV)} | 5.0A |
| V _{RRM} | 80V |
| I _{FSM} | 120A |
| V _F at I _f =5.0A,125°C | 0.50V |
| T _{JMAX} | 150°C |

MAXIMUM RATINGS

(Ratings at 25°C ambient temperature unless otherwise specified)

| Parameter | Symbol | SB580L | Unit |
|--|--------------------|------------|------|
| Maximum repetitive peak reverse voltage | V _{RRM} | 80 | V |
| Maximum average forward rectified current 0.375"(9.5mm) lead length(see fig.1) | I _{F(AV)} | 5.0 | A |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC method at rated TL) | I _{FSM} | 120 | A |
| Operating junction temperature range | T _J | -55 to+150 | °C |
| Storage temperature range | T _{stg} | -55 to+150 | °C |

RATINGS AND CHARACTERISTIC OF SB580L

ELECTRICAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ Unless otherwise noted)

| Parameter | Test Conditions | Symbol | TYP. | MAX. | Unit |
|-------------------------------|---------------------|---------------------|------|----------------|------|
| Instantaneous forward voltage | $I_F=5.0\text{A}$ | V_F ¹⁾ | 0.54 | 0.58 | V |
| | | | 0.52 | — | |
| | | | 0.50 | — | |
| | | | 0.45 | — | |
| | | | 0.38 | — | |
| | $I_F=2.0\text{A}$ | | 0.35 | — | |
| | I_R ²⁾ | 20 | 50 | $\mu\text{ A}$ | |
| | | 1.7 | — | mA | |
| | | 6.5 | — | | |
| Typical junction capacitance | 4V, 1MHz | C_J | 340 | | pF |

Notes: 1.Pulse test: 300 μs pulse width,1% duty cycle

2.Pulse test: pulse width $\leqslant 40\text{ms}$

THERMAL CHARACTERISTICS ($T_A=25^\circ\text{C}$ Unless otherwise noted)

| Parameter | Symbol | SB580L | Unit |
|--|-----------------|--------|---------------------------|
| Typical thermal resistance ³⁾ | $R_{\theta JA}$ | 25.0 | $^\circ\text{C}/\text{W}$ |
| | $R_{\theta JL}$ | 8.0 | |

3.Thermal resistance from junction to lead vertical P.C.B. mounted , 0.375"(9.5mm)lead length

RATINGS AND CHARACTERISTIC OF SB580L

FIG.1-FORWARD CURRENT DERATING CURVE

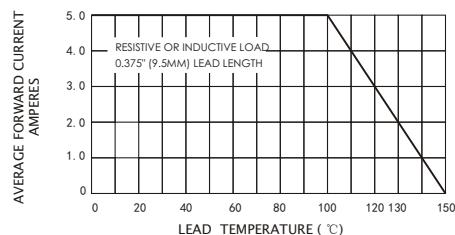


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

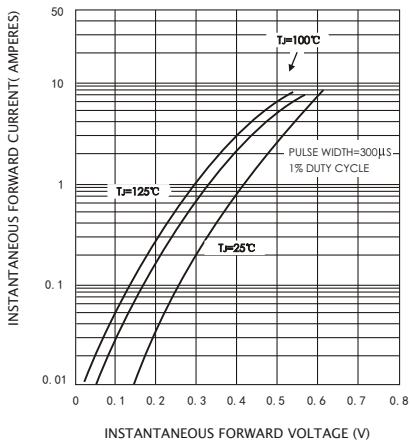


FIG.5-TYPICAL JUNCTION CAPACITANCE

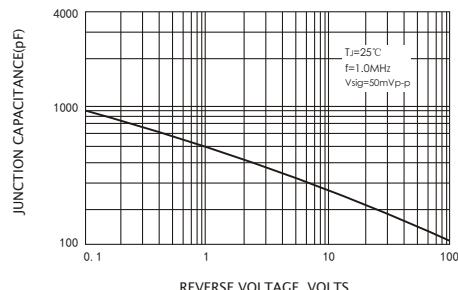


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

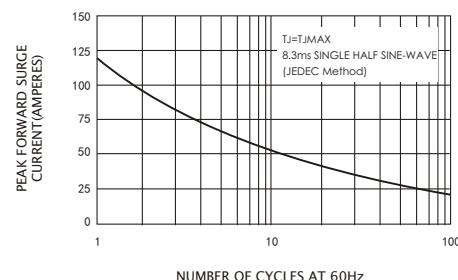


FIG.4-TYPICAL REVERSE CHARACTERISTICS

